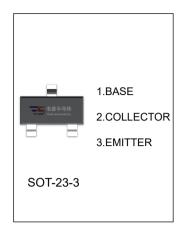


# 2SA1037K TRANSISTOR (PNP)

#### **FEATURES**

- Excellent h<sub>FE</sub> linearity.
- Complments the 2SC2412K



## MAXIMUM RATINGS (Ta=25℃ unless otherwise noted)

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	-60	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-50	V
V <sub>EBO</sub>	Emitter-Base Voltage	-6	V
Ic	Collector Current -Continuous	-150	mA
P <sub>C</sub>	Collector Power Dissipation	400	mW
T <sub>J</sub> ,T <sub>stg</sub>	Operation Junction and Storage Temperature Range	-55-150	℃

### **ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)**

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> =-50μA,I <sub>E</sub> =0	-60			V
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> =-1mA,I <sub>B</sub> =0	-50			V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =-50μA,I <sub>C</sub> =0	-6			V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> =-60V,I <sub>E</sub> =0			-0.1	μA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =-6V,I <sub>C</sub> =0			-0.1	μΑ
DC current gain	h <sub>FE</sub>	V <sub>CE</sub> =-6V,I <sub>C</sub> =-1mA	120		560	
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =-50mA,I <sub>B</sub> =-5mA			-0.5	<b>V</b>
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> =-12V,I <sub>C</sub> =-2mA,f=30MHz		140		MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> =-12V,I <sub>E</sub> =0,f=1MHz		4.0	5.0	pF

## **CLASSIFICATION OF h**<sub>FE</sub>

Rank	Q	R	s
Range	120 - 270	180 - 390	270 - 560



